

## T495C106K016ATA450

T495 Auto, Tantalum, MnO<sub>2</sub> Tantalum, Commercial Grade, 10 uF, 10%, 16 VDC, SMD, MnO<sub>2</sub>, Molded, Low ESR, Auto, AEC-Q200, 450 mOhms, 2.8 mm, 1.3 mm, 2312 / 6032



Click [here](#) for the 3D model.

### General Information

Series	T495 Auto
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, MnO <sub>2</sub> , Molded, Low ESR, Auto, AEC-Q200
Features	Low ESR, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	224.48 mg

### Specifications

Capacitance	10 uF
Tolerance	10%
Voltage DC	16 VDC (85C), 10.72 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	8% 120Hz 25C
Failure Rate	N/A
ESR	450 mOhms (100kHz 25C)
Ripple Current	494 mA (rms, 100kHz 25C), 444.6 mA (rms, 85C), 197.6 mA (rms, 125C)
Leakage Current	1.6 uA (5min 25°C)

### Dimensions

L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
A	2.9mm MIN
B	0.5mm +/-0.15mm
E	2.4mm REF
G	2.8mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

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